TEXAS INSTRUMENTS

SN74LVC125A

SCAS290Q –JANUARY 1993–REVISED JANUARY 2015

SN74LVC125A Quadruple Bus Buffer Gate With 3-State Outputs

1 Features

- 3-State Outputs
- Separate $\overline{\text{OE}}$ for all 4 buffers
- Operates From 1.65 V to 3.6 V
- Specified From –40°C to 85°C and –40°C to 125°C
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 4.8 ns at 3.3 V
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot) > 2 V at V_{CC} = 3.3 V, T_A = 25°C
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model
  - 200-V Machine Model
  - 1000-V Charged-Device Model

2 Applications

- Cable Modem Termination Systems
- IP Phones: Wired and Wireless
- Optical Modules
- Optical Networking:
  - EPON or Video Over Fiber
- Point-to-Point Microwave Backhaul
- Power: Telecom DC/DC Modules:
  - Analog or Digital
- Private Branch Exchanges (PBX)
- TETRA Base Stations
- Telecom Base Band Units
- Telecom Shelters:
  - Filter Unit s
  - Power Distribution Units (PDU)
  - Power Monitoring Units (PMU)
  - Wireless Battery Monitoring
  - Remote Electrical Tilt Units (RET)
  - Remote Radio Units (RRU)
  - Tower Mounted Amplifiers (TMA)
- Vector Signal Analyzers and Generators
- Video Conferencing: IP-Based HD
- WiMAX and Wireless Infrastructure Equipment
- Wireless Communications Testers
- xDSL Modems and DSLAM

3 Description

This quadruple bus buffer gate is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74LVC125A device features independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable ($\overline{\text{OE}}$) input is high.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

Device Information[1]

PART NUMBER	PACKAGE (PIN)	BODY SIZE
SN74LVC125A	SOIC (14)	8.65 mm × 3.91 mm
	SSOP (14)	6.20 mm × 5.30 mm
	SOP (14)	10.30 mm × 5.30 mm
	TSSOP (14)	5.00 mm × 4.40 mm
	VQFN (14)	3.50 mm × 3.50 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.
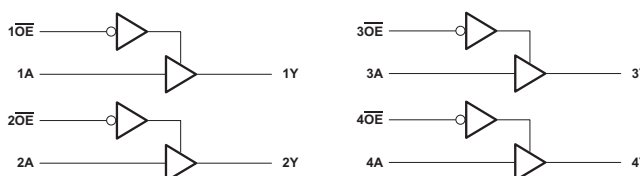
4 Simplified Schematic

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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5 Revision History

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6 Pin Configuration and Functions

D, DB, NS, OR PW PACKAGE
(TOP VIEW)

```
         ┌───┬───┐
1OE  [ 1 │   │14 ] VCC
1A   [ 2 │   │13 ] 4OE
1Y   [ 3 │   │12 ] 4A
2OE  [ 4 │   │11 ] 4Y
2A   [ 5 │   │10 ] 3OE
2Y   [ 6 │   │ 9 ] 3A
GND  [ 7 │   │ 8 ] 3Y
         └───┴───┘
```

RGY PACKAGE
(TOP VIEW)

```
         1OE    VCC
          1     14
1A   [2          13] 4OE
1Y   [3          12] 4A
2OE  [4          11] 4Y
2A   [5          10] 3OE
2Y   [6           9] 3A
          7      8
         GND    3Y
```
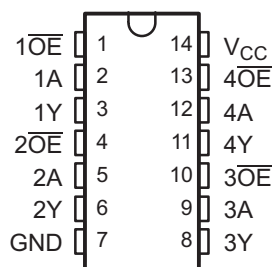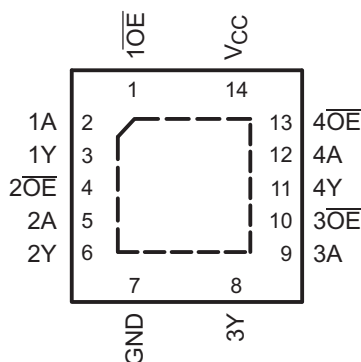
Pin Functions

PIN		TYPE	DESCRIPTION
NAME	D, DB, NS, PW and RGY		
1A	2	I	Input
1OE	1	I	Output enable
1Y	3	O	Output
2A	5	I	Input
2OE	4	I	Output enable
2Y	6	O	Output
3A	9	I	Input
3OE	10	I	Output enable
3Y	8	O	Output
4A	12	I	Input
4OE	13	I	Output enable
4Y	11	O	Output
GND	7	—	Ground
VCC	14	—	Power pin

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		−0.5	6.5	V
V_I	Input voltage range[2]		−0.5	6.5	V
V_O	Output voltage range[2][3]		−0.5	V_{CC} + 0.5	V
I_{IK}	Input clamp current	$V_I < 0$		−50	mA
I_{OK}	Output clamp current	$V_O < 0$		−50	mA
I_O	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA
P_{tot}	Power dissipation	T_A = −40°C to 125°C[4][5]		500	mW
T_{stg}	Storage temperature range		−65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
(3) The value of V_{CC} is provided in the *Recommended Operating Conditions* table.
(4) For the D package: above 70°C, the value of P_{tot} derates linearly with 8 mW/K.
(5) For the DB, NS, and PW packages: above 60°C, the value of P_{tot} derates linearly with 5.5 mW/K.

7.2 ESD Ratings

PARAMETER		DEFINITION	VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins[1]	2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins[2]	1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

Product Folder Links: *SN74LVC125A*

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)[1]

			T_A = 25°C		−40°C to 85°C		−40°C to 125°C		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	Operating	1.65	3.6	1.65	3.6	1.65	3.6	V
		Data retention only	1.5		1.5		1.5		
V_{IH}	High-level input voltage	V_{CC} = 1.65 V to 1.95 V	0.65 × V_{CC}		0.65 × V_{CC}		0.65 × V_{CC}		V
		V_{CC} = 2.3 V to 2.7 V	1.7		1.7		1.7		
		V_{CC} = 2.7 V to 3.6 V	2		2		2		
V_{IL}	Low-level input voltage	V_{CC} = 1.65 V to 1.95 V		0.35 × V_{CC}		0.35 × V_{CC}		0.35 × V_{CC}	V
		V_{CC} = 2.3 V to 2.7 V		0.7		0.7		0.7	
		V_{CC} = 2.7 V to 3.6 V		0.8		0.8		0.8	
V_I	Input voltage		0	5.5	0	5.5	0	5.5	V
V_O	Output voltage		0	V_{CC}	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 1.65 V		−4		−4		−4	mA
		V_{CC} = 2.3 V		−8		−8		−8	
		V_{CC} = 2.7 V		−12		−12		−12	
		V_{CC} = 3 V		−24		−24		−24	
I_{OL}	Low-level output current	V_{CC} = 1.65 V		4		4		4	mA
		V_{CC} = 2.3 V		8		8		8	
		V_{CC} = 2.7 V		12		12		12	
		V_{CC} = 3 V		24		24		24	
Δt/Δv	Input transition rise or fall rate			8		8		8	ns/V

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

7.4 Thermal Information

THERMAL METRIC[1]	D[2]	DB[2]	NS[2]	PW[2]	RGY[3]	UNIT
	14 PINS					
$R_{\theta JA}$ Junction-to-ambient thermal resistance	86	96	76	113	47	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.
(2) The package thermal impedance is calculated in accordance with JESD 51-7.
(3) The package thermal impedance is calculated in accordance with JESD 51-5.

7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	T_A = 25°C MIN	T_A = 25°C TYP	T_A = 25°C MAX	−40°C to 85°C MIN	−40°C to 85°C MAX	−40°C to 125°C MIN	−40°C to 125°C MAX	UNIT
V_{OH}	I_{OH} = −100 µA	1.65 V to 3.6 V	V_{CC} − 0.2			V_{CC} − 0.2		V_{CC} − 0.3		V
	I_{OH} = −4 mA	1.65 V	1.29			1.2		1.05		
	I_{OH} = −8 mA	2.3 V	1.9			1.7		1.55		
	I_{OH} = −12 mA	2.7 V	2.2			2.2		2.05		
		3 V	2.4			2.4		2.25		
	I_{OH} = −24 mA	3 V	2.3			2.2		2		
V_{OL}	I_{OL} = 100 µA	1.65 V to 3.6 V			0.1		0.2		0.3	V
	I_{OL} = 4 mA	1.65 V			0.24		0.45		0.6	
	I_{OL} = 8 mA	2.3 V			0.3		0.7		0.75	
	I_{OL} = 12 mA	2.7 V			0.4		0.4		0.6	
	I_{OL} = 24 mA	3 V			0.55		0.55		0.8	
I_I	V_I = 5.5 V or GND	3.6 V			±1		±5		±20	µA
I_{OZ}	V_O = V_{CC} or GND	3.6 V			±1		±10		±20	µA
I_{CC}	V_I = V_{CC} or GND, I_O = 0	3.6 V			1		10		40	µA
ΔI_{CC}	One input at V_{CC} − 0.6 V, Other inputs at V_{CC} or GND	2.7 V to 3.6 V			500		500		5000	µA
C_i	V_I = V_{CC} or GND	3.3 V		5						pF

7.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	T_A = 25°C MIN	T_A = 25°C TYP	T_A = 25°C MAX	−40°C to 85°C MIN	−40°C to 85°C MAX	−40°C to 125°C MIN	−40°C to 125°C MAX	UNIT
t_{pd}	A	Y	1.8 V ± 0.15 V	1	4.5	11.8	1	12.3	1	13.8	ns
			2.5 V ± 0.2 V	1	2.7	5.8	1	6.3	1	8.4	
			2.7 V	1	3	5.3	1	5.5	1	7	
			3.3 V ± 0.3 V	1	2.5	4.6	1	4.8	1	6	
t_{en}	$\overline{OE}$	Y	1.8 V ± 0.15 V	1	4.3	13.8	1	14.3	1	15.8	ns
			2.5 V ± 0.2 V	1	2.7	6.9	1	7.4	1	9.5	
			2.7 V	1	3.3	6.4	1	6.6	1	8.5	
			3.3 V ± 0.3 V	1	2.4	5.2	1	5.4	1	7	
t_{dis}	$\overline{OE}$	Y	1.8 V ± 0.15 V	1	4.3	10.6	1	11.1	1	12.6	ns
			2.5 V ± 0.2 V	1	2.2	5.1	1	5.6	1	7.7	
			2.7 V	1	2.5	4.8	1	5	1	6.5	
			3.3 V ± 0.3 V	1	2.4	4.4	1	4.6	1	6	
$t_{sk(o)}$			3.3 V ± 0.3 V					1		1.5	ns

7.7 Operating Characteristics

T_A = 25°C

PARAMETER		TEST CONDITIONS	V_{CC}	TYP	UNIT
C_{pd}	Power dissipation capacitance per gate	f = 10 MHz	1.8 V	7.4	pF
			2.5 V	11.3	
			3.3 V	15	

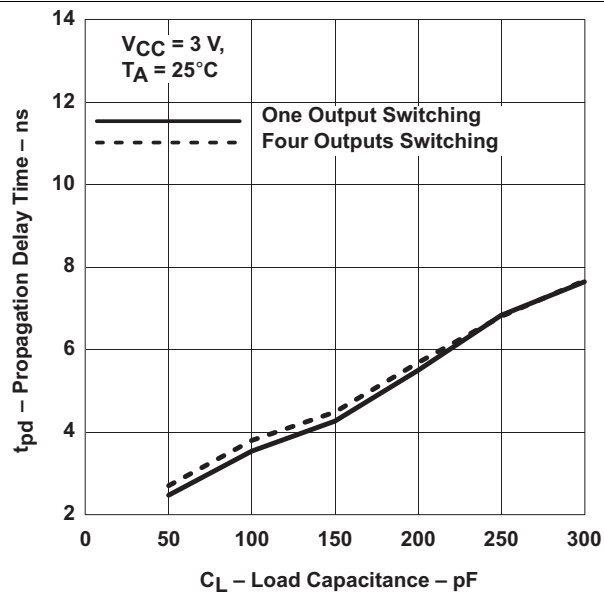Product Folder Links: SN74LVC125A

7.8 Typical Characteristics

Figure 1. Propagation Delay (Low to High Transition) vs Load Capacitance
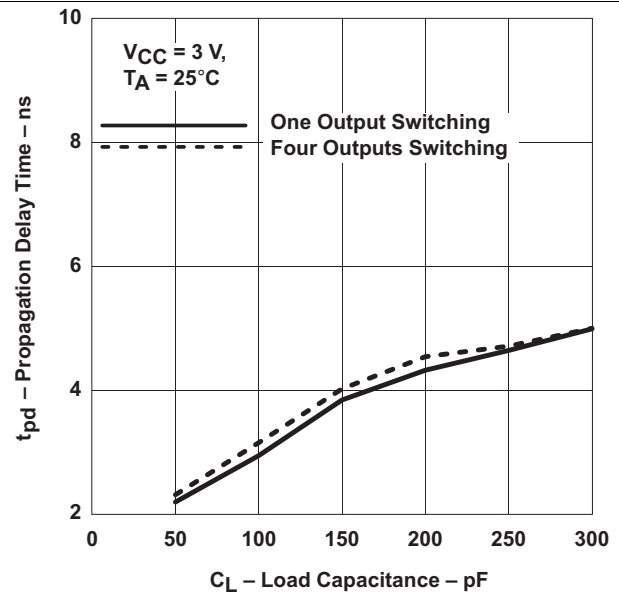
**Figure 2. Propagation Delay (High to Low Transition) vs Load Capacitance**

Product Folder Links: *SN74LVC125A*

8 Parameter Measurement Information

LOAD CIRCUIT

From Output Under Test — C_L (see Note A) — R_L — R_L — S1 — V_{LOAD} / Open / GND
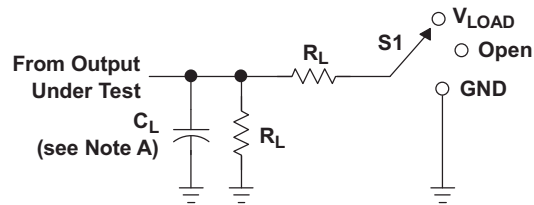
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_Δ
	V_I	t_r/t_f					
1.8 V ± 0.15 V	V_{CC}	≤2 ns	$V_{CC}/2$	2 × V_{CC}	30 pF	1 kΩ	0.15 V
2.5 V ± 0.2 V	V_{CC}	≤2 ns	$V_{CC}/2$	2 × V_{CC}	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V ± 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
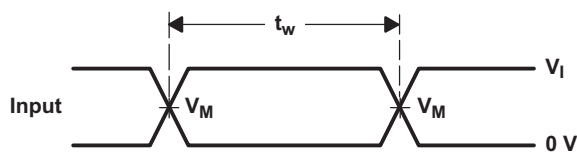
**VOLTAGE WAVEFORMS
PULSE DURATION**
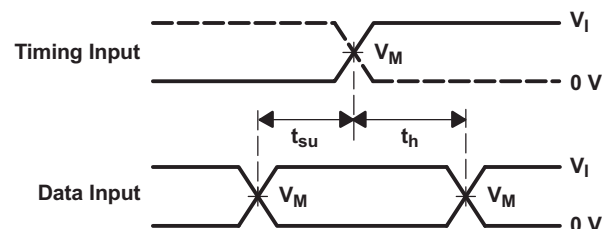
**VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES**
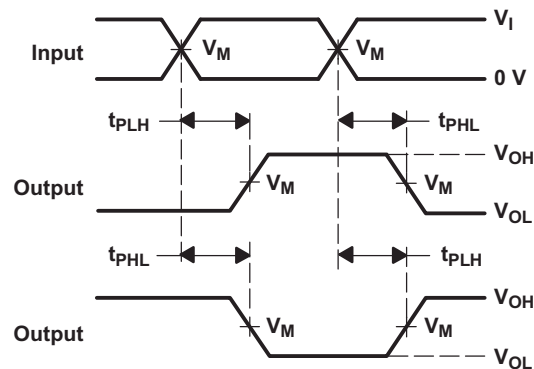
**VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS**
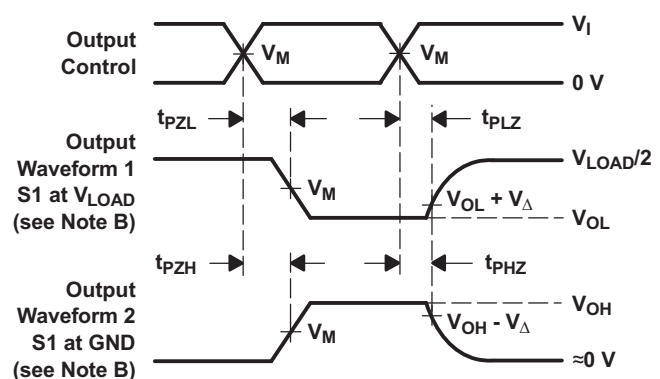
**VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING**

NOTES: A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR≤ 10 MHz, Z_O = 50 Ω.

D. The outputs are measured one at a time, with one transition per measurement.

E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.

F. t_{PZL} and t_{PZH} are the same as t_{en}.

G. t_{PLH} and t_{PHL} are the same as t_{pd}.

H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

Product Folder Links: *SN74LVC125A*

9 Detailed Description

9.1 Overview

The SN74LVC125A device is a quadruple bus buffer gate featuring independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable ($\overline{OE}$) input is high. When $\overline{OE}$ is low, the respective gate passes the data from the A input to its Y output. To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

9.2 Functional Block Diagram
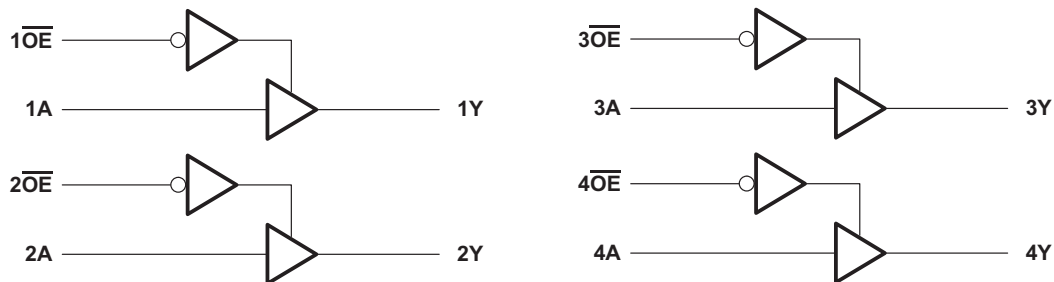
9.3 Feature Description

- Wide operating voltage range
  - Operates from 1.65 V to 5.5 V
- Allows down voltage translation
- Inputs accept voltages to 5.5 V

9.4 Device Functional Modes

Table 1. Function Table

INPUTS		OUTPUT
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

Product Folder Links: *SN74LVC125A*

10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

SN74LVC125A is a high drive CMOS device that can be used for a multitude of bus interface type applications where output drive or PCB trace length is a concern. The inputs can accept voltages to 5.5 V at any valid V_{CC} making it ideal for down translation.

10.2 Typical Application
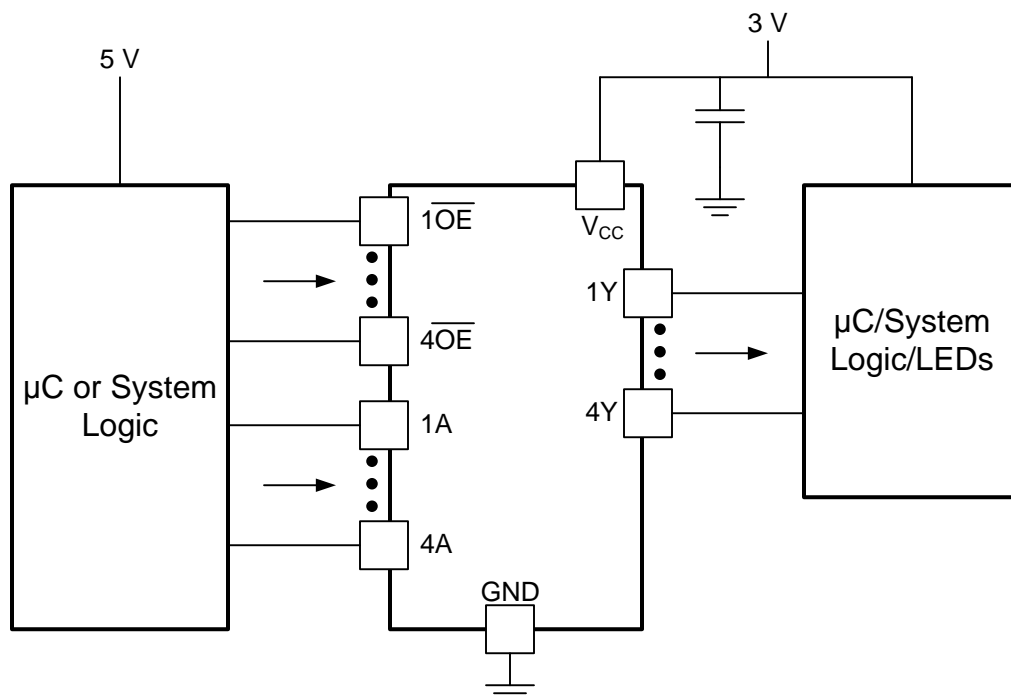
Figure 4. Typical Application Schematic

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

1. Recommended Input Conditions:
   - For rise time and fall time specifcations, see (Δt/ΔV) in the *Recommended Operating Conditions* table.
   - For specified high and low levels, see (V_{IH} and V_{IL}) in the *Recommended Operating Conditions* table.
   - Inputs are overvoltage tolerant allowing them to go as high as (V_I max) in the *Recommended Operating Conditions* table at any valid V_{CC}.
2. Recommend Output Conditions:
   - Load currents should not exceed (I_O max) per output and should not exceed (Continuous current through V_{CC} or GND) total current for the part. These limits are located in the *Absolute Maximum Ratings* table.

Product Folder Links: *SN74LVC125A*

Typical Application (continued)

- – Outputs should not be pulled above V_{CC}.
- – Series resistors on the output may be used if the user desires to slow the output edge signal or limit the output current.

10.2.3 Application Curves
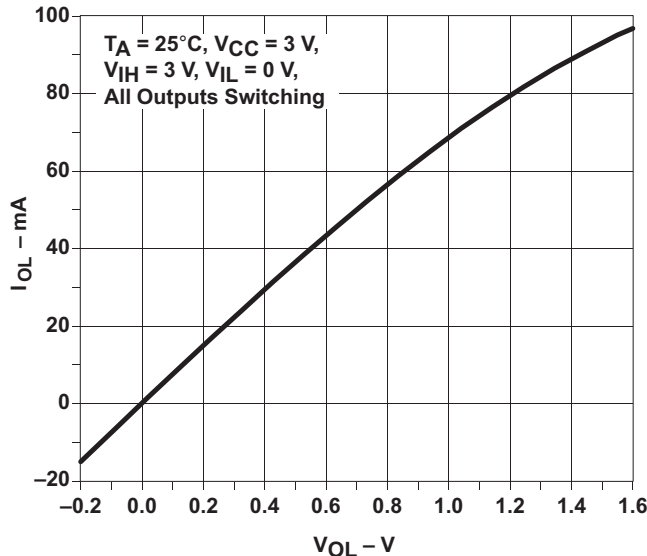
Figure 5. Output Drive Current (I_{OL})
vs LOW-level Output Voltage (V_{OL})
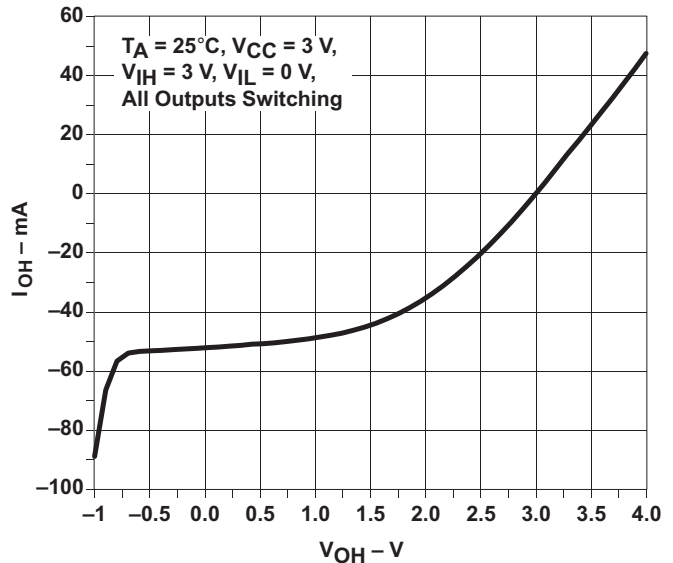
Figure 6. Output Drive Current (I_{OH})
vs HIGH-level Output Voltage (V_{OH})

11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1 µF capacitor is recommended. If there are multiple V_{CC} terminals then 0.01 µF or 0.022 µF capacitors are recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. Multiple bypass capacitors may be paralleled to reject different frequencies of noise. The bypass capacitor should be installed as close to the power terminal as possible for the best results.

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 7 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC}, whichever makes more sense or is more convenient.

Product Folder Links: *SN74LVC125A*

12.2 Layout Example

Figure 7. Layout Diagram

Product Folder Links: *SN74LVC125A*
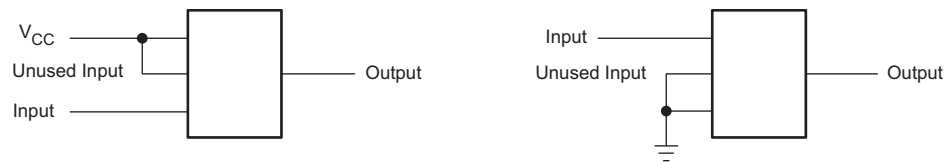
13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — *TI Glossary.*

This glossary lists and explains terms, acronyms and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC125AD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125ADBRG4	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125ADE4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125ADG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125ADRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125ADRG3	ACTIVE	SOIC	D	14	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125ADRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125ADT	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125ADTG4	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125ANSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC125A	Samples
SN74LVC125APW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125APWE4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125APWG4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125APWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125APWRG3	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-1-260C-UNLIM		LC125A	Samples
SN74LVC125APWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125APWT	ACTIVE	TSSOP	PW	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC125APWTE4	ACTIVE	TSSOP	PW	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125APWTG4	ACTIVE	TSSOP	PW	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125A	Samples
SN74LVC125ARGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LC125A	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC125A :

● Automotive: SN74LVC125A-Q1

● Enhanced Product: SN74LVC125A-EP

NOTE: Qualified Version Definitions:

    ● Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

    ● Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

User Direction of Feed
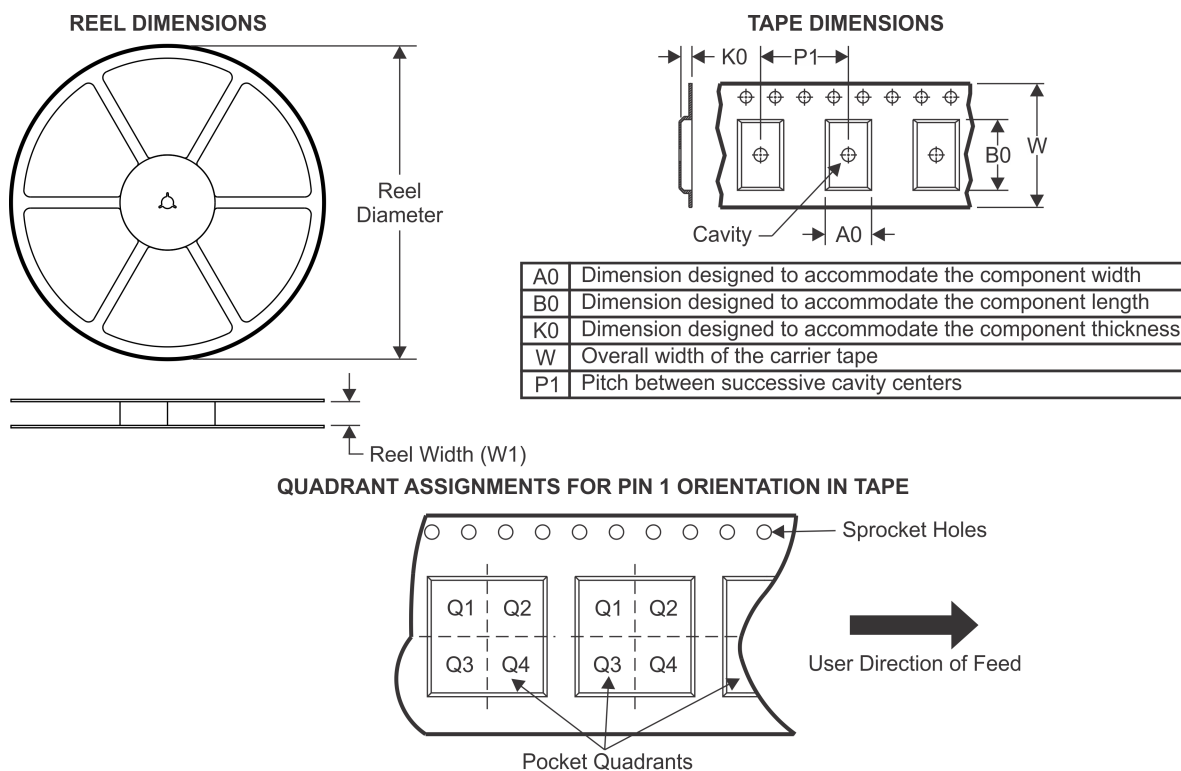
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC125ADR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
SN74LVC125ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC125ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC125ADRG3	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.3	8.0	16.0	Q1
SN74LVC125ADRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC125ADRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC125ADT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC125ANSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LVC125APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125APWRG3	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125APWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC125ADR	SOIC	D	14	2500	364.0	364.0	27.0
SN74LVC125ADR	SOIC	D	14	2500	333.2	345.9	28.6
SN74LVC125ADR	SOIC	D	14	2500	853.0	449.0	35.0
SN74LVC125ADRG3	SOIC	D	14	2500	364.0	364.0	27.0
SN74LVC125ADRG4	SOIC	D	14	2500	333.2	345.9	28.6
SN74LVC125ADRG4	SOIC	D	14	2500	853.0	449.0	35.0
SN74LVC125ADT	SOIC	D	14	250	210.0	185.0	35.0
SN74LVC125ANSR	SO	NS	14	2000	853.0	449.0	35.0
SN74LVC125APWR	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74LVC125APWR	TSSOP	PW	14	2000	853.0	449.0	35.0
SN74LVC125APWRG3	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74LVC125APWRG4	TSSOP	PW	14	2000	853.0	449.0	35.0
SN74LVC125APWT	TSSOP	PW	14	250	853.0	449.0	35.0
SN74LVC125ARGYR	VQFN	RGY	14	3000	853.0	449.0	35.0

RGY (S−PVQFN−N14)   PLASTIC QUAD FLATPACK NO−LEAD

3,65 / 3,35   A

B

13   9

14   8

3,65 / 3,35

1   7

2   6

Pin 1 Index Area
Top and Bottom

F

1,00 / 0,80

0,20 Nominal
Lead Frame

Seating Plane

0,08 C

0,05 / 0,00
Seating Height

C

2,00

0,50

14X 0,50 / 0,30

2   6

1   7

THERMAL PAD

SIZE AND SHAPE
SHOWN ON SEPRATE SHEET

1,50

14   8

13   9

14X 0,30 / 0,18

⊕ | 0,10 Ⓜ | C | A | B |
  | 0,05 Ⓜ | C |

Bottom View

4203539−2/I 06/2011

NOTES: A.   All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
          B.   This drawing is subject to change without notice.
          C.   QFN (Quad Flatpack No−Lead) package configuration.
          D.   The package thermal pad must be soldered to the board for thermal and mechanical performance.
          E.   See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
          F.   Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated.
                The Pin 1 identifiers are either a molded, marked, or metal feature.
          G.   Package complies to JEDEC MO−241 variation BA.

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RGY (S−PVQFN−N14)   PLASTIC QUAD FLATPACK NO−LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No−Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

2,05±0,10

2,05±0,10

Exposed Thermal Pad
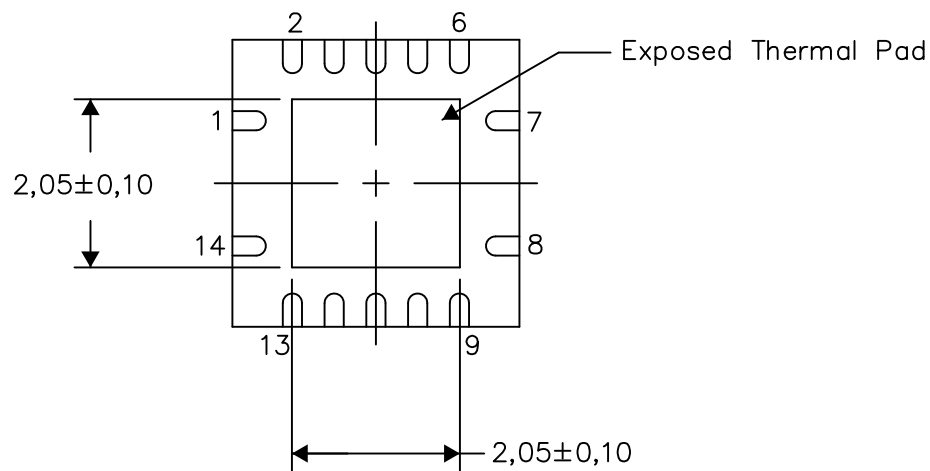
Bottom View

Exposed Thermal Pad Dimensions

4206353−2/P   03/14

NOTE: All linear dimensions are in millimeters

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RGY (S−PVQFN−N14) PLASTIC QUAD FLATPACK NO−LEAD

Example Board Layout

4,30

4,30

2,60

1,50

2,05

2,05

Note D

8x0,50

0.28

Example Stencil Design
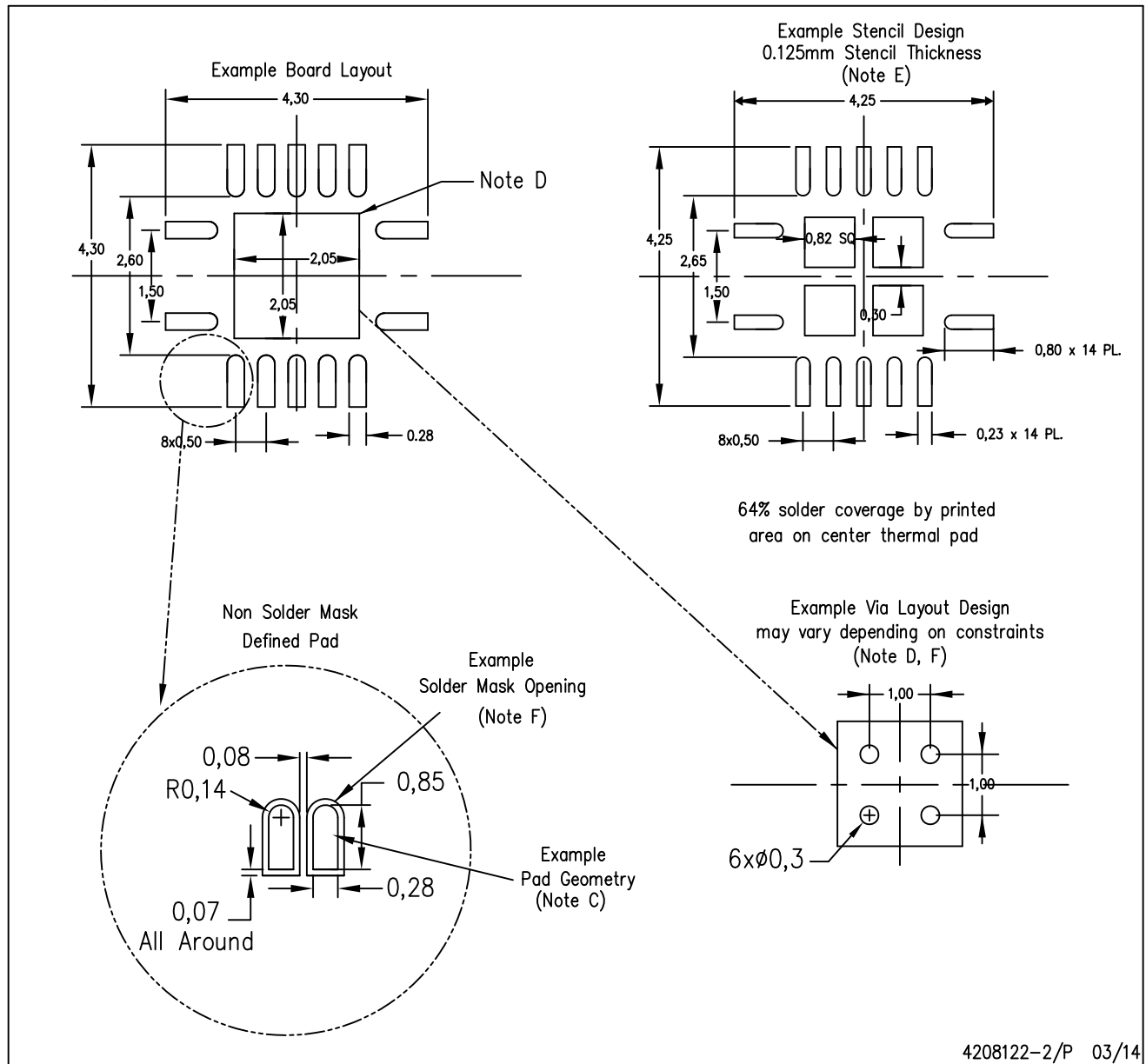0.125mm Stencil Thickness
(Note E)

4,25

4,25

2,65

1,50

0,82 SQ

0,50

0,80 x 14 PL.

8x0,50

0,23 x 14 PL.

64% solder coverage by printed
area on center thermal pad

Non Solder Mask
Defined Pad

Example
Solder Mask Opening
(Note F)

0,08

R0,14

0,85

0,07

0,28

All Around

Example
Pad Geometry
(Note C)

Example Via Layout Design
may vary depending on constraints
(Note D, F)

1,00

1,00

6x∅0,3

4208122−2/P 03/14

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC−7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat−Pack
   QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets
   for specific thermal information, via requirements, and recommended board layout.
   These documents are available at www.ti.com <http://www.ti.com>.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
   contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

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MECHANICAL DATA

PINS **	14	16	20	24
DIM				
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03
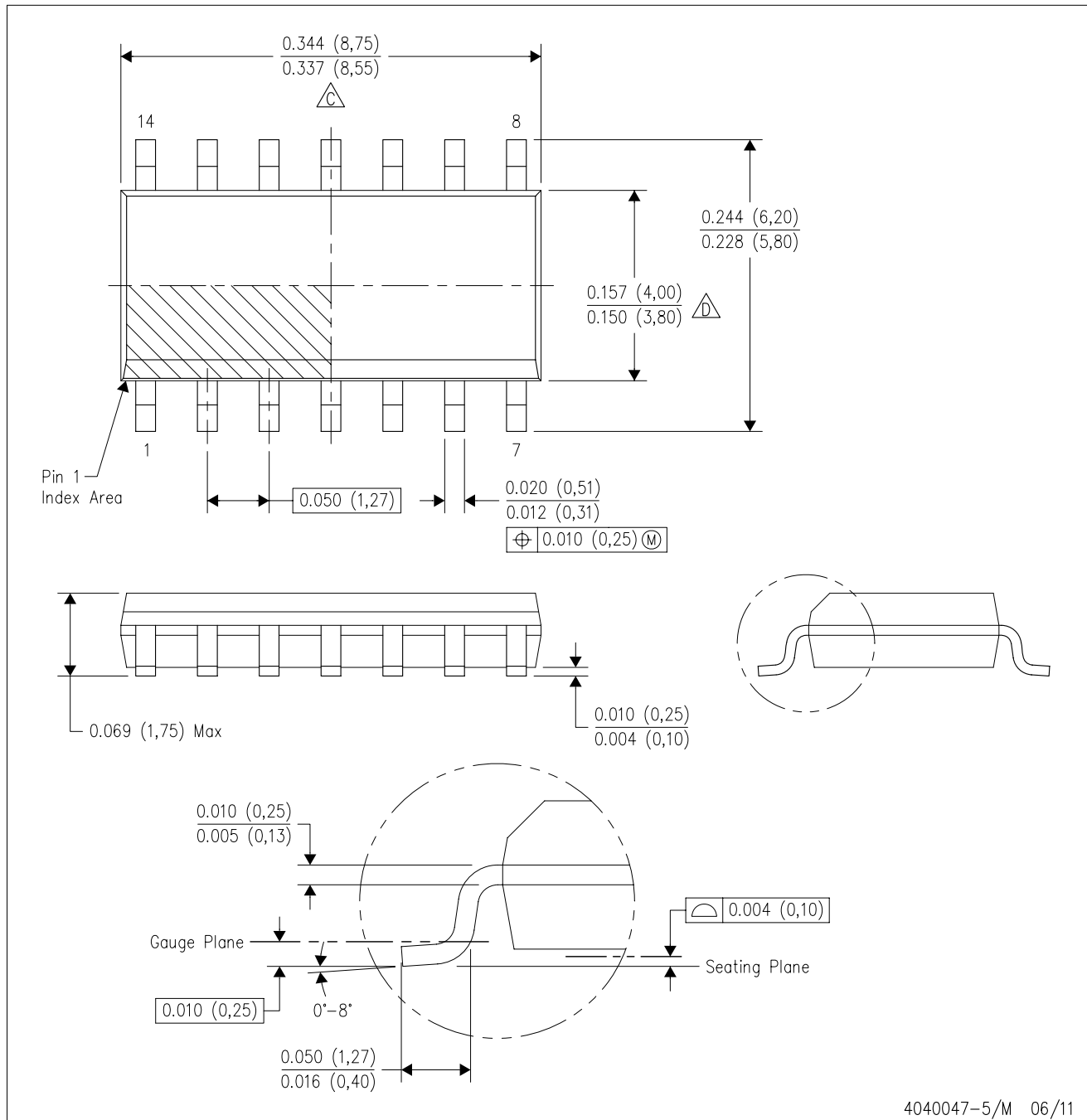
NOTES: A.   All linear dimensions are in millimeters.
         B.   This drawing is subject to change without notice.
         C.   Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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D (R−PDSO−G14)   PLASTIC SMALL OUTLINE

$$\frac{0.344\ (8,75)}{0.337\ (8,55)}$$

⟨C⟩

14   8

$$\frac{0.244\ (6,20)}{0.228\ (5,80)}$$

$$\frac{0.157\ (4,00)}{0.150\ (3,80)}$$ ⟨D⟩

1   7

Pin 1
Index Area

0.050 (1,27)

$$\frac{0.020\ (0,51)}{0.012\ (0,31)}$$

⊕ | 0.010 (0,25) Ⓜ

0.069 (1,75) Max

$$\frac{0.010\ (0,25)}{0.004\ (0,10)}$$

$$\frac{0.010\ (0,25)}{0.005\ (0,13)}$$

⬛ | 0.004 (0,10)

Gauge Plane

Seating Plane

0.010 (0,25)   0°–8°

$$\frac{0.050\ (1,27)}{0.016\ (0,40)}$$

4040047−5/M   06/11

NOTES: A.   All linear dimensions are in inches (millimeters).
         B.   This drawing is subject to change without notice.
       ⟨C⟩   Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall
              not exceed 0.006 (0,15) each side.
       ⟨D⟩   Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
         E.   Reference JEDEC MS−012 variation AB.

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D (R−PDSO−G14)   PLASTIC SMALL OUTLINE

Example Board Layout
(Note C)

Stencil Openings
(Note D)

12x1,27

14x0,55

14x1,50

12x1,27

5,40

5,40

Example
Non Soldermask Defined Pad

Example
Pad Geometry
(See Note C)

0,60

1,55

Example
Solder Mask Opening
(See Note E)

0.07
All Around

4211283−3/E 08/12

NOTES: A.   All linear dimensions are in millimeters.
          B.   This drawing is subject to change without notice.
          C.   Publication IPC−7351 is recommended for alternate designs.
          D.   Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
               contact their board assembly site for stencil design recommendations. Refer to IPC−7525 for other stencil recommendations.
          E.   Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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PW (R−PDSO−G14)   PLASTIC SMALL OUTLINE

0,65

0,30
0,19

⊕ 0,10 Ⓜ

14   8

D   4,50   6,60
     4,30   6,20

1   7

5,10
4,90

C

0,15 NOM

Gage Plane

0°−8°

0,25

0,75
0,50

1,20 MAX

0,15
0,05

Seating Plane

◯ 0,10

4040064−3/G   02/11

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
         B. This drawing is subject to change without notice.
         C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall
             not exceed 0,15 each side.
         D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
         E. Falls within JEDEC MO−153

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PW (R−PDSO−G14)   PLASTIC SMALL OUTLINE

Example Board Layout
(Note C)

Stencil Openings
(Note D)

12x0,65

14x0,30

12x0,65

14x1,55

5,60

5,60

Example
Non Soldermask Defined Pad

Example
Pad Geometry
(See Note C)

0,35

1,60

Example
Solder Mask Opening
(See Note E)

0,07
All Around

4211284−2/G   08/15

NOTES: A.   All linear dimensions are in millimeters.
         B.   This drawing is subject to change without notice.
         C.   Publication IPC−7351 is recommended for alternate designs.
         D.   Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
              contact their board assembly site for stencil design recommendations. Refer to IPC−7525 for other stencil recommendations.
         E.   Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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DB (R-PDSO-G)**   **PLASTIC SMALL-OUTLINE**

28 PINS SHOWN

PINS ** DIM	14	16	20	24	28	30	38
A MAX	6,50	6,50	7,50	8,50	10,50	10,50	12,90
A MIN	5,90	5,90	6,90	7,90	9,90	9,90	12,30

4040065 /E 12/01

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-150

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